

Vishay Semiconductors

ADD-A-PAK Generation VII Power Modules Schottky Rectifier, 200 A



PRODUCT SUMMARY			
I _{F(AV)}	200 A		

MECHANICAL DESCRIPTION

The ADD-A-PAK generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation
- · Low thermal resistance
- UL pending
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- · Easy mounting on heatsink

ELECTRICAL DESCRIPTION

The VSKCS201.. Schottky rectifier common cathode has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	200	А		
V _{RRM}		45	V		
I _{FSM}	t _p = 5 μs sine	8600	А		
V _F	100 Apk, T _J = 125 °C	0.69	V		
T _J	Range	- 55 to 175	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VSKCS201/045	UNITS		
Maximum DC reverse voltage	V_{R}	45	V		
Maximum working peak reverse voltage	V_{RWM}	45	V		

VSKCS201/045

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ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS VALUES		VALUES	UNITS	
Maximum average	per module		EO % duty quals at T 122 % vector gular vacuations		200	200	
forward current	per leg	I _{F(AV)} 50 % duty cycle at T _C = 123 °C, rectangular waveform		100			
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	8600	А		
non-repetitive surge current		I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	1850		
Non-repetitive avalanche energ	Jy	E _{AS}	$T_J = 25$ °C, $I_{AS} = 24$ A, L = 1 mH		270	mJ	
Repetitive avalanche current		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \text{ x } V_B$ typical		А		

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Marian markaning day	V _{FM}	100 A	T _J = 25 °C	0.72	V
		200 A		1.04	
Maximum forward voltage drop		100 A	T _J = 125 °C	0.69	
		200 A		0.98	
Maximum rayaraa laakaga aurrant		T _J = 25 °C	V _R = Rated V _R	10	mA
Maximum reverse leakage current	I _{RM}	T _J = 125 °C		90	IIIA
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		5200	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		7.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs
Maximum RMS insulation voltage	V _{INS}	50 Hz		3000 (1 min) 3600 (1 s)	V

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range)	T _J , T _{Stg}		- 55 to 175	°C
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	0.52	°C/W
Typical thermal resistance, case to heatsink per module		R _{thCS}		0.1	
Approximate weight				75	g
Approximate weight				2.7	oz.
Mounting torque ± 10 % to heatsink busbar		A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for	4	Nm	
	busbar		the spread of the compound.	3	INIII
Case style			JEDEC	TO-240AA co	mpatible



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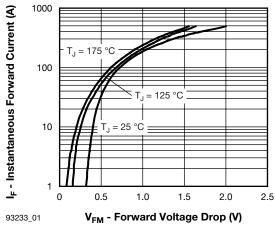


Fig. 1 - Maximum Forward Voltage Drop Characteristics

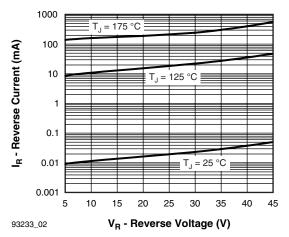


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

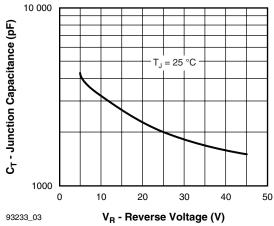


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

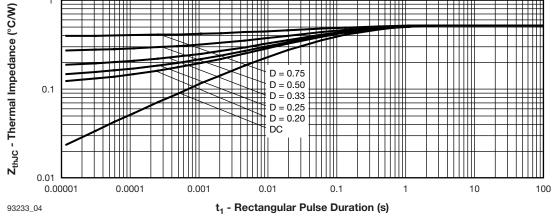


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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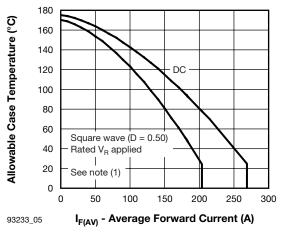


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

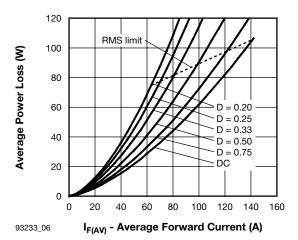


Fig. 6 - Forward Power Loss Characteristics

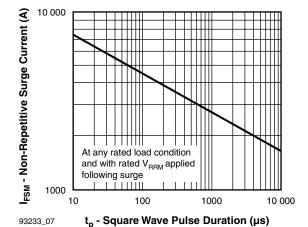


Fig. 7 - Maximum Non-Repetitive Surge Current

D.U.T. High-speed switch $R_g = 25 \Omega$ Freewheel diode $V_d = 25 V_d$ $V_d = 25 V_d$

Fig. 8 - Unclamped Inductive Test Circuit

Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

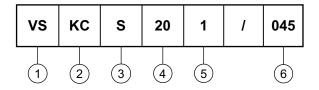


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ORDERING INFORMATION TABLE

Device code



1 - Vishay HPP

2 - Circuit configuration:

KC = ADD-A-PAK - 2 diodes/common cathode

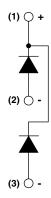
3 - S = Schottky diode

Average current rating (20 = 200 A)

Product silicon identification

6 - Voltage rating (045 = 45 V)

CIRCUIT CONFIGURATION



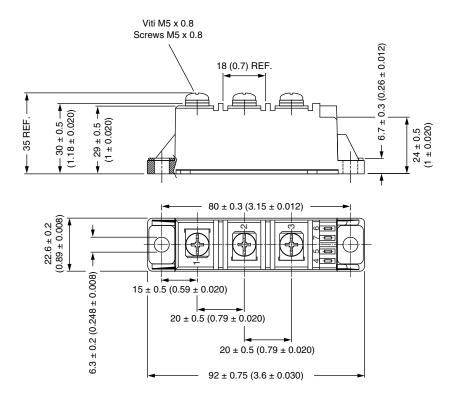
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95369			



Vishay Semiconductors

ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)







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